

# FPF1013/4 IntelliMAX<sup>™</sup> 1V Rated Advanced Load Management Products

package.

### Features

- 0.8V to 1.8V Input Voltage Range
- Typical R<sub>DS(ON)</sub> = 17mΩ @ V<sub>ON</sub> V<sub>IN</sub> = 2.0V
- Output Discharge Function

FAIRCHILD SEMICONDUCTOR

- Internal Pull-down at ON Pin
- Accurate Slew Rate Controlled Turn-on time
- Low < 1µA Quiescent Current
- ESD Protected, above 8000V HBM, 2000V CDM
- RoHS Compliant
- Free from Halogenated Compounds and Antimony Oxides

### Applications

PDAs

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- Cell Phones
- GPS Devices
- MP3 Players
- Digital Cameras
- Notebook Computer



BOTTOM

Pin 1

**General Description** 

directly with low voltage control signals.

The FPF1013/4 series is an IntelliMAX advanced slew rate loadswitch offering a very low operating voltage. These devices

consist of a 17mΩ N-channel MOSFET that supports an input

voltage up to 2.0V. These slew rate devices control the switch

turn-on and prevent excessive in-rush current from the supply

rails. The input voltage range operates from 0.8V to 1.8V to

fulfill today's lowest Ultraportable Device's supply requirements. Switch control is via a logic input (ON) capable of interfacing

The FPF1014 has an On-Chip pull down allowing for quick and

controlled output discharge when switch is turned off. The FPF1013/4 series is available in a space-saving 1X1.5 CSP-6L



## **Typical Application Circuit**



### **Ordering Information**

Part	Switch	Turn-on Time	Output Discharge	ON Pin Activity	Package	
FPF1013	17mΩ, NMOS	43µs	N/A	Active HI	CSP1X1.5	
FPF1014	17mΩ, NMOS	43µs	60Ω	Active HI	CSP1X1.5	

**FPF1013/4 IntelliMAX<sup>TM</sup> 1V Rated Advanced Load Management Products** 



Note 1: Package power dissipation on 1 square inch pad, 2 oz. copper board

CDM

Recommended Operating Range						
Min	Max	Unit				
0.8	1.8	V				
-40	85	°C				
	Min   0.8   -40	Min Max   0.8 1.8   -40 85				

## **Electrical Characteristics**

$v_{\rm N} = 0.0$ to 1.0v, $r_{\rm A} = -40$ to $\pm 0.0$ c unless otherwise noted. Typical values are at $v_{\rm N} = 1.0$ and $r_{\rm A} = 2.0$	$V_{IN} = 0.8$ to 1.8V, $T_{f}$	$_{\rm A}$ = -40 to +85°C unless	otherwise noted. Typic	al values are at V <sub>IN</sub> =1.8	SV and T <sub>A</sub> = 25°0
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Parameter	Symbol	Conditions	Min	Тур	Max	Units
Basic Operation	1					
Operating Voltage	V <sub>IN</sub>		0.8		1.8	V
	V <sub>ON(MIN)</sub>	V <sub>IN</sub> = 0.8V	1.8	2.8	4.0	V
ON Input voltage	V <sub>ON(MAX)</sub>	V <sub>IN</sub> = 1.8V (Note 2)	2.8	3.8	4.0	V
Operating Current	I <sub>CC</sub>	$V_{IN}$ = 1V, $V_{ON}$ = 3.3V, $V_{OUT}$ = Open			1	μA
Quiescent Current	۱ <sub>Q</sub>	V <sub>IN</sub> = 1V, V <sub>ON</sub> = GND, V <sub>OUT</sub> = Open			2	μA
Off Switch Current	ISWOFF	V <sub>IN</sub> = 1.8V, V <sub>ON</sub> = GND, V <sub>OUT</sub> = GND			2	μA
On Registeres	Б	$V_{IN}$ = 1V, $V_{ON}$ = 3V, $I_{OUT}$ = 1A, $T_A$ = 25C		17	27	m0
On-Resistance	RON	V <sub>IN</sub> = 1V, V <sub>ON</sub> = 2.3V, I <sub>OUT</sub> = 1A, T <sub>A</sub> = 25°C		25	38	11122
Output Pull Down Resistance	R <sub>PD</sub>	$V_{IN}$ = 1V, $V_{ON}$ = 0V, $I_{OUT}$ = 1mA, $T_A$ = 25°C, FPF1014		60	120	Ω
	V	V <sub>IN</sub> = 0.8V, R <sub>L</sub> = 1KΩ			0.3	V
ON Input Logic Low Voltage	۷IL	V <sub>IN</sub> = 1.8V, R <sub>L</sub> = 1KΩ			0.8	v
ON Input Leakage		V <sub>ON</sub> = V <sub>IN</sub> or GND	-1		1	μA
<b>Dynamic</b> (V <sub>IN</sub> = 1.0V, V <sub>ON</sub> = 3	.0V, T <sub>A</sub> = 25	°C)				
	т	$R_{L} = 500\Omega, C_{L} = 0.1\mu F$		28		
V <sub>OUT</sub> Rise Time	<sup>I</sup> R	$R_{L} = 3.3\Omega, C_{L} = 10\mu F$		38		μs
T	-	$R_{L} = 500\Omega, C_{L} = 0.1\mu F$		43		
rum on nime	ON	$R_{L} = 3.3\Omega, C_{L} = 10\mu F$		58		μs
	-	FPF1014, R <sub>L</sub> = 500Ω, C <sub>L</sub> = 0.1μF		14		
heet4U com	١F	FPF1014, R <sub>L</sub> = 3.3Ω, C <sub>L</sub> = 10μF		76		μs
Turn Off Time	т	FPF1014, R <sub>L</sub> = 500Ω, C <sub>L</sub> = 0.1μF		50		
	OFF	FPF1014, R <sub>L</sub> = 3.3Ω, C <sub>L</sub> = 10μF		96		μs

Note 2:  $V_{ON(MAX)}$  is limited by the absolute rating.



4



FPF1013/4 IntelliMAX<sup>™</sup> 1V Rated Advanced Load Management Products



## **Description of Operation**

The FPF1013/4 are low  $R_{DS(ON)}$  N-Channel load switches with controlled turn-on. The core of each device is a  $17m\Omega$  (V<sub>IN</sub> = 1V, V<sub>ON</sub> = 3V) N-Channel MOSFET and is customized for a low input operating range of 0.8 to 1.8V. The ON pin controls the state of the switch.

The FPF1014 contains a  $60\Omega(typ)$  on-chip resistor which is connected internally from  $V_{OUT}$  to GND for quick output discharge when the switch is turned off.

### **On/Off Control**

The ON pin is active high and it controls the state of the switch. Applying a continuous high signal will hold the switch in the ON state. In order to minimize the switch on resistance, the ON pin voltage should exceed the input voltage by 2V. This device is compatible with a GPIO (General Purpose Input/Output) port, where the logic voltage level can be configured to  $4V \ge V_{ON} \ge V_{IN}+2V$  and power consumed is less than 1µA in steady state.

## Application Information

## **Typical Application**





### Input Capacitor

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns-on, a capacitor must be placed between  $V_{IN}$  and GND. For minimized voltage drop, especially when the operating voltage approaches 1V a 10µF ceramic capacitor should be placed close to the  $V_{IN}$  pins. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop during higher current modes of operation.

### **Output Capacitor**

A 0.1µF capacitor, C<sub>L</sub>, should be placed between V<sub>OUT</sub> and GND. This capacitor will prevent parasitic board inductance from forcing V<sub>OUT</sub> below GND when the switch turns-off. If the application has a capacitive load, the FPF1014 can be used to discharged that load through an on-chip output discharge path.

#### **Board Layout**

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces or large copper planes for all pins (V<sub>IN</sub>, V<sub>OUT</sub>, ON and GND) will help minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

#### **Improving Thermal Performance**

An improper layout could result in higher junction temperature. This concern applies when continuous operation current is set to maximum allowed current and switch turns into a large capacitive load that introduce high inrush current in the transient. Since FPF1013/4 does not have thermal shutdown feature a proper layout can essentially reduce power dissipation of the switch in transient and prevents switch to exceed the maximum absolute power dissipation of 1.2W.

The V<sub>IN</sub>, V<sub>OUT</sub> and GND pins will dissipate most of the heat generated during a high load current condition. The layout suggested in Figure 16 provides each pin with adequate copper so that heat may be transferred as efficiently as possible out of the device. The ON pin trace may be laid-out diagonally from the device to maximize the area available to the ground pad. Placing the input and output capacitors as close to the device as possible also contributes to heat dissipation, particularly during high load currents.



### Demo Board Layout

FPF1013/4 Demo board has the components and circuitry to demonstrate FPF1013/4 load switches functions. Thermal performance of the board is improved using a few techniques recommended in the layout recommendations section of datasheet.



Figure 17. FPF1013/4 Demo Board Layout

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#### PRODUCT STATUS DEFINITIONS

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.